March 2013



# Features

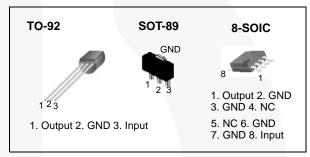
FAIRCHILD

SEMICONDUCTOR

- Maximum Output Current of 100 mA
- Output Voltage of 5 V, 6 V, 8 V, 12 V, and 15 V
- Thermal Overload Protection
- Short-Circuit Current Limiting
- Output Voltage Offered in ±5% Tolerance

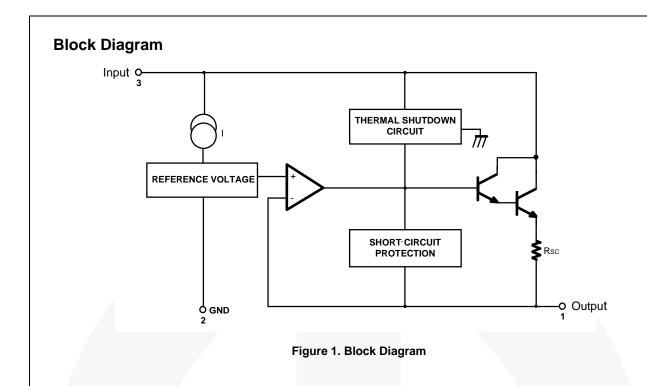
# Description

The MC78LXXA / LM78LXXA series of fixed-voltage monolithic integrated circuit voltage regulators are suitable for applications that required supply current up to 100 mA.



Product Number	Package	Packing Method	Output Voltage Tolerance	<b>Operating Temperature</b>
LM78L05ACZ		Bulk		
LM78L05ACZX		Tape & Reel		
LM78L05ACZXA		Ammo		
LM78L12ACZ		Bulk		
LM78L12ACZX		Tape & Reel		
MC78L05ACP	TO-92	Bulk		
MC78L05ACPXA		Ammo		
MC78L06ACP		Bulk	±5%	0 to +125°C
MC78L08ACP		Bulk		
MC78L15ACP		Bulk		
MC78L15ACPXA		Ammo		
MC78L05ACD		Rail		
MC78L05ACDX	8-SOIC	Tape & Reel		
MC78L05ACHX	00 T 00	Tape & Reel	1	
MC78L08ACHX	SOT-89	Tape & Reel	1	

# **Ordering Information**



# Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	ſ	Value	Unit
V		$V_0 = 5 V \text{ to } 8 V$	30	V
VI	Input Voltage	V <sub>O</sub> = 12 V to 15 V	35	V
Τ <sub>J</sub>	Operating Junction Temperature Range	0 to +150	°C	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-Case	TO-92	50	°C/W
		TO-92	150	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction-Air	SOT-89	225	°C/W
		8-SOIC	160	°C/W

# Electrical Characteristics (MC78L05A / LM78L05A)

 $V_1 = 10 \text{ V}, I_0 = 40 \text{ mA}, 0^{\circ}\text{C} \le T_1 \le 125^{\circ}\text{C}, C_1 = 0.33 \mu\text{F}, C_0 = 0.1 \mu\text{F}, \text{ unless otherwise specified}.$ 

Symbol	Parameter		Conditions		Min.	Тур.	Max.	Unit
Vo	Output Voltage		T <sub>J</sub> = 25°C		4.8	5.0	5.2	V
A)/	Line Regulation <sup>(1)</sup>		T _ 25°C	$7 \text{ V} \leq \text{V}_{I} \leq 20 \text{ V}$		8	150	mV
$\Delta V_O$			T <sub>J</sub> = 25°C	$8 \text{ V} \leq \text{V}_{I} \leq 20 \text{ V}$		6	100	mV
ΔV <sub>O</sub>	Load Regulation <sup>(1)</sup>		T <sub>.1</sub> = 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		11	60	mV
Δvo			$1_{\rm J} = 25 \rm C$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$		5.0	30.0	mV
V	Output Voltage		$7 \text{ V} \leq \text{V}_{\text{I}} \leq 20 \text{ V}$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$			5.25	V
Vo			$7 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{MAX}}^{(2)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	4.75		5.25	V
Ι <sub>Q</sub>	Quiescent Current		$T_J = 25^{\circ}C$			2.0	5.5	mA
$\Delta I_Q$	Quiescent Current	With Line	$8 \text{ V} \leq \text{V}_{I} \leq 20 \text{ V}$				1.5	mA
$\Delta I_Q$	Change	With Load	$1 \text{ mA} \le I_O \le 40 \text{ mA}$	N Contraction of the second se			0.1	mA
V <sub>N</sub>	Output Noise Voltage		T <sub>A</sub> = 25°C, 10 Hz	≤ f ≤ 100 kHz		40		μV/Vo
$\Delta V_O / \Delta T$	Temperature Coefficient of VO		l <sub>O</sub> = 5 mA			-0.65		mV/°C
RR	Ripple Rejection		f = 120 Hz, 8 V ≤ V	$V_{\rm I} \le 18 \text{ V}, \text{ T}_{\rm J} = 25^{\circ}\text{C}$	41	80		dB
V <sub>D</sub>	Dropout Voltage		T <sub>J</sub> = 25°C			1.7		V

Notes:

1. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 2. Power dissipation  $P_D \le 0.75$  W.

# **Electrical Characteristics (MC78L06A)**

 $V_I$  = 12 V,  $I_O$  = 40 mA, 0°C ≤  $T_J$  ≤ 125°C,  $C_I$  = 0.33  $\mu$ F,  $C_O$  = 0.1  $\mu$ F, unless otherwise specified.

Symbol	Paramete	er		Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T <sub>J</sub> = 25°C	T <sub>J</sub> = 25°C		6.0	6.25	V
A) /	Line Regulation <sup>(3)</sup>		T 2500	$8.5 \text{ V} \le \text{V}_{\text{I}} \le 20 \text{ V}$		64	175	mV
$\Delta V_O$			T <sub>J</sub> = 25°C	$9 \text{ V} \leq \text{V}_{I} \leq 20 \text{ V}$		54	125	mV
A) /	Load Regulation <sup>(3)</sup>		T <sub>J</sub> = 25°C	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		12.8	80.0	mV
$\Delta V_{O}$				1 mA ≤ I <sub>O</sub> ≤ 70 mA		5.8	40.0	mV
V	Output Voltage		$8.5 V \leq V_1 \leq$	≤ 20 V, 1 mA ≤ I <sub>O</sub> ≤ 40 mA	5.7		6.3	V
V <sub>O</sub>			$8.5 V \le V_1 \le$	$\leq V_{MAX}^{(4)}$ , 1 mA $\leq I_{O} \leq$ 70 mA	5.7		6.3	V
			T <sub>J</sub> = 25°C				5.5	mA
Ι <sub>Q</sub>	Quiescent Current		T <sub>J</sub> = 125°C	;		3.9	6.0	mA
$\Delta I_Q$	Quiescent Current	With Line	$9 V \le V_{I} \le 2$	20 V			1.5	mA
$\Delta I_Q$	Change	With Load	1 mA ≤ I <sub>O</sub> s	≤ 40 mA			0.1	mA
V <sub>N</sub>	Output Noise Voltage		T <sub>A</sub> = 25°C,	10 Hz $\leq$ f $\leq$ 100 kHz		40		μV/Vo
$\Delta V_O / \Delta T$	Temperature Coefficient of V <sub>O</sub>		I <sub>O</sub> = 5 mA			0.75		mV/°0
RR	Ripple Rejection		f = 120 Hz,	$10 \text{ V} \le \text{V}_{\text{I}} \le 20 \text{ V}, \text{T}_{\text{J}} = 25^{\circ}\text{C}$	40	46		dB
VD	Dropout Voltage		T <sub>J</sub> = 25°C			1.7		V

# Notes:

The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.
Power dissipation P<sub>D</sub> ≤ 0.75 W.

# **Electrical Characteristics (MC78L08A)**

 $V_I = 14 \text{ V}, I_O = 40 \text{ mA}, 0^{\circ}\text{C} \le T_I \le 125^{\circ}\text{C}, C_I = 0.33 \mu\text{F}, C_O = 0.1 \mu\text{F}, \text{ unless otherwise specified.}$ 

Symbol	Parameter		Conditions			Тур.	Max.	Unit
V <sub>O</sub>	Output Voltage		T <sub>J</sub> = 25°C		7.7	8.0	8.3	V
A) /			(5)	$10.5~V \leq V_{I} \leq 23~V$		10	175	mV
$\Delta V_O$	Line Regulation <sup>(5)</sup>		T <sub>J</sub> = 25°C	$11~V \le V_I \le 23~V$		8	125	mV
A) /	Load Regulation <sup>(5)</sup>		T,₁ = 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		15	80	mV
$\Delta V_O$			$I_{\rm J} = 25^{\circ} \rm C$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$		8	40	mV
V	Output Voltage		$10.5V \le V_1 \le 23V$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$	7.6		8.4	V
Vo			$10.5V \le V_I \le V_{MAX}^{(6)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	7.6		8.4	V
Ι <sub>Q</sub>	Quiescent Current		T <sub>J</sub> = 25°C			2.0	5.5	mA
$\Delta I_Q$	Quiescent Current	With Line	$11~V \le V_I \le 23~V$				1.5	mA
$\Delta I_Q$	Change	With Load	$1 \text{ mA} \le I_O \le 40 \text{ mA}$				0.1	mA
V <sub>N</sub>	Output Noise Voltage		$T_A = 25^{\circ}C$ , 10 Hz $\leq$ f	≤100 kHz		60		μV/Vo
$\Delta V_O / \Delta T$	Temperature Coefficient of V <sub>O</sub>		l <sub>O</sub> = 5 mA			-0.8		mV/°C
RR	Ripple Rejection		f = 120 Hz, 11 V $\leq$ V <sub>I</sub>	$\leq$ 21 V, T <sub>J</sub> = 25°C	39	70		dB
VD	Dropout Voltage		T <sub>J</sub> = 25°C			1.7		V

Notes:

5. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 6. Power dissipation  $P_D \le 0.75$  W.

# Electrical Characteristics (MC78L12A / LM78L12A)

 $V_1 = 19 V$ ,  $I_0 = 40 mA$ ,  $0^{\circ}C \le T_1 \le 125^{\circ}C$ ,  $C_1 = 0.33 \mu$ F,  $C_0 = 0.1 \mu$ F, unless otherwise specified.

Symbol	Parame	Parameter		tions	Min.	Тур.	Max.	Unit
V <sub>O</sub>	Output Voltage		$T_J = 25^{\circ}C$		11.5	12.0	12.5	V
41/	Line Regulation (7)		T <sub>.1</sub> = 25°C	$14.5~V \leq V_{I} \leq 27~V$		20	250	mV
ΔV <sub>O</sub>	Line Regulation .	,	$1_{\rm J} = 25$ C	$16 \text{ V} \le \text{V}_{\text{I}} \le 27 \text{ V}$		15	200	mV
ΔV <sub>O</sub>	Load Regulation <sup>(7)</sup>		T <sub>.1</sub> = 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		20	100	mV
Δv0			1j = 25 C	$1 \text{ mA} \le I_O \le 40 \text{ mA}$		10	50	mV
Vo	Output Voltage		14.5 V $\le$ V <sub>I</sub> $\le$ 27 V	$1 \text{ mA} \le I_O \le 40 \text{ mA}$	11.4		12.6	V
۷V			$14.5 V \le V_I \le V_{MAX}^{(8)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	11.4		12.6	V
١ <sub>Q</sub>	Quiescent Curren	t	$T_J = 25^{\circ}C$			2.1	6.0	mA
$\Delta I_Q$	Quiescent	With Line	$16 \text{ V} \leq \text{V}_{\text{I}} \leq 27 \text{ V}$				1.5	mA
$\Delta I_Q$	Current Change	With Load	$1 \text{ mA} \le I_O \le 40 \text{ mA}$				0.1	mA
V <sub>N</sub>	Output Noise Voltage		$T_A = 25^{\circ}C$ , 10 Hz $\leq f$	≤ 100 kHz		80		μV/Vo
$\Delta V_O / \Delta T$	Temperature Coefficient of V <sub>O</sub>		l <sub>O</sub> = 5 mA			-1.0		mV/°C
RR	Ripple Rejection		f = 120 Hz, 15 V $\leq$ V <sub>1</sub>	$\leq 25 \text{ V}, \text{ T}_{\text{J}} = 25^{\circ}\text{C}$	37	65		dB
V <sub>D</sub>	Dropout Voltage		$T_J = 25^{\circ}C$			1.7		V

Notes:

7. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 8. Power dissipation  $P_D \le 0.75$  W.

# **Electrical Characteristics (MC78L15A)**

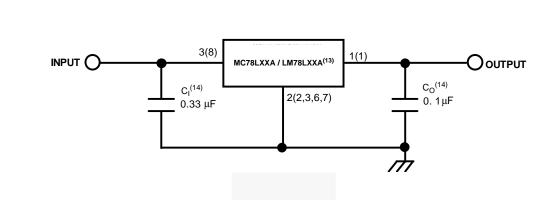
 $V_I = 23 \text{ V}, I_O = 40 \text{ mA}, 0^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}, C_I = 0.33 \mu\text{F}, C_O = 0.1 \mu\text{F}, \text{ unless otherwise specified.}$ 

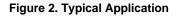
Symbol	Parame	ter	Condit	ions	Min.	Тур.	Max.	Unit
V <sub>O</sub>	Output Voltage		T <sub>J</sub> = 25°C		14.4	15.0	15.6	V
A) /	Line Regulation <sup>(9)</sup>		T 25%C	$17.5~V \le V_I \le 30~V$		25	300	mV
$\Delta V_O$			T <sub>J</sub> = 25°C	$20 \text{ V} \leq \text{V}_{\text{I}} \leq 30 \text{ V}$		20	250	mV
A) /	Load Regulation <sup>(9)</sup>		T - 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		25	150	mV
$\Delta V_O$			T <sub>J</sub> = 25°C	$1 \text{ mA} \le I_O \le 40 \text{ mA}$		12	75	mV
V	Output Voltage		$17.5 \text{ V} \le \text{V}_{\text{I}} \le 30 \text{ V}$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$	14.25		15.75	V
Vo			$17.5 \text{ V} \le \text{V}_{\text{I}} \le \text{V}_{\text{MAX}}^{(10)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	14.25		15.75	V
Ι <sub>Q</sub>	Quiescent Curren	t	$T_J = 25^{\circ}C$			2.1	6.0	mA
$\Delta I_Q$	Quiescent	With Line	$20 \text{ V} \leq \text{V}_{\text{I}} \leq 30 \text{ V}$				1.5	mA
$\Delta I_Q$	Current Change	With Load	$1 \text{ mA} \le I_O \le 40 \text{ mA}$				0.1	mA
V <sub>N</sub>	Output Noise Voltage		$T_A = 25^{\circ}C$ , 10 Hz $\leq$ f $\leq$	100 kHz		90		μV/Vo
$\Delta V_O / \Delta T$	Temperature Coefficient of V <sub>O</sub>		l <sub>O</sub> = 5 mA			-1.3		mV/°C
RR	Ripple Rejection		f = 120 Hz, 18.5 V $\leq$ V <sub>I</sub>	≤28.5 V, T <sub>J</sub> = 25°C	34	60		dB
VD	Dropout Voltage		$T_J = 25^{\circ}C$			1.7		V

Notes:

9. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 10. Power dissipation  $P_D \le 0.75$  W.

# MC78LXXA / LM78LXXA — 3-Terminal 0.1 A Positive Voltage Regulator

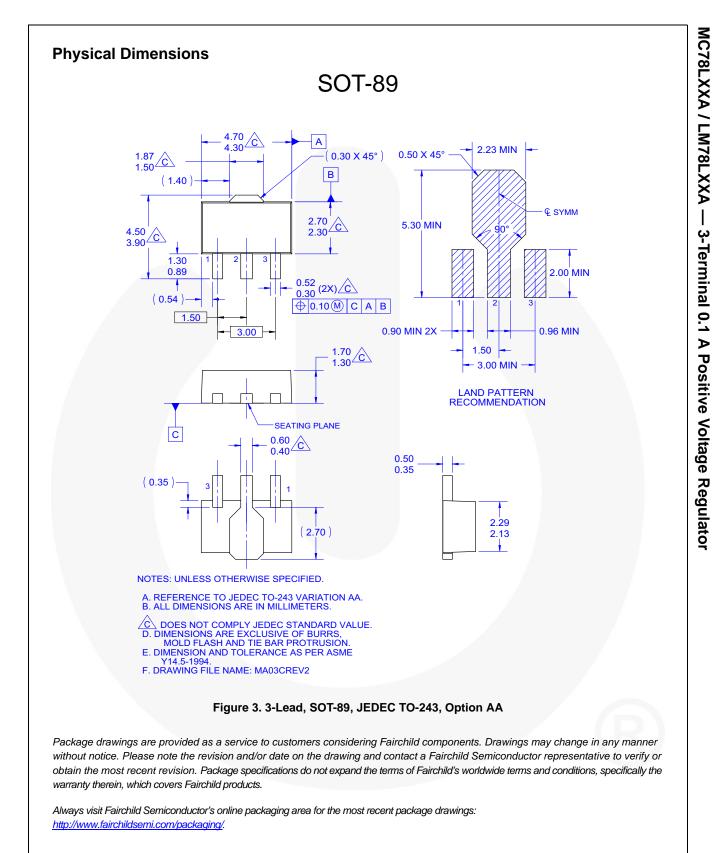




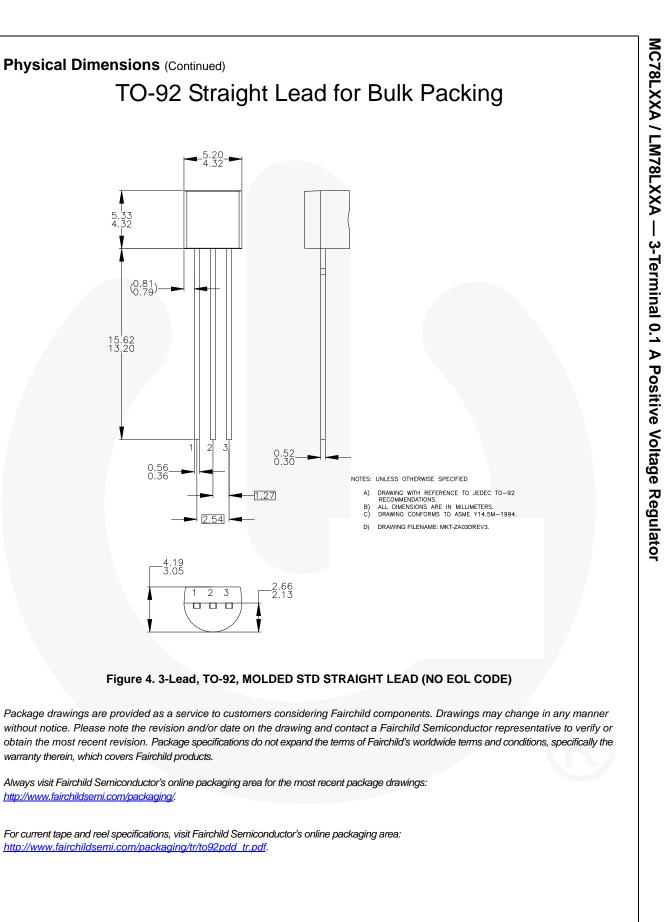
# Notes:

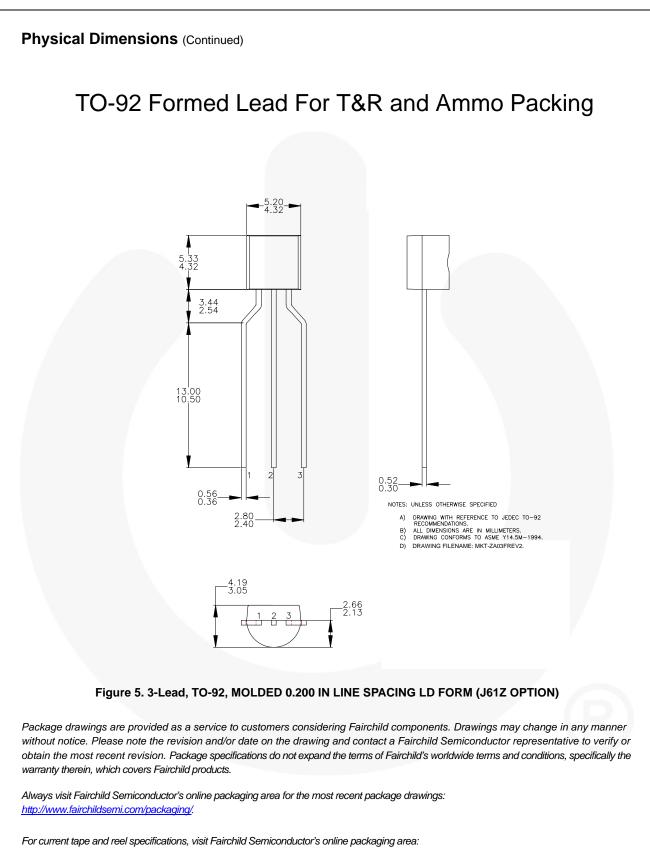
**Typical Application** 

- 13. To specify an output voltage, substitute voltage value for "XX".
- 14. C<sub>1</sub> is required if the regulator is located an appreciable distance from the power supply filter. Though C<sub>0</sub> is not needed for stability, it improves transient response. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulator.

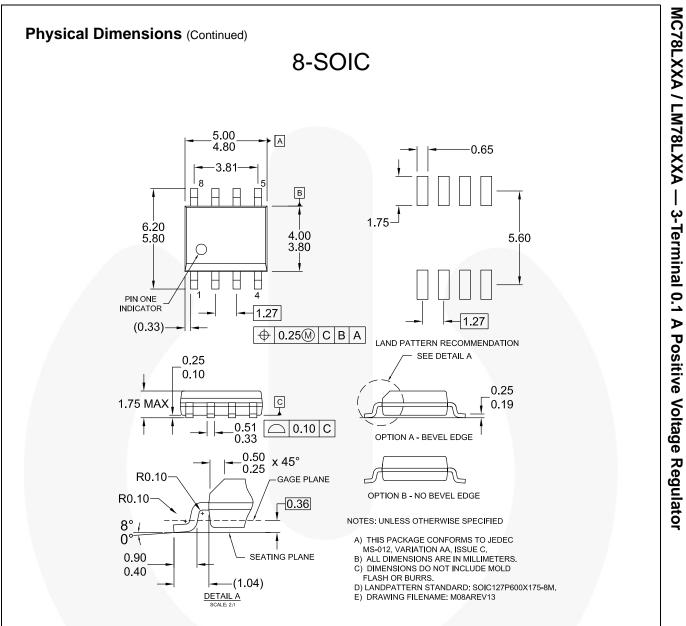


For current tape and reel specifications, visit Fairchild Semiconductor's online packaging area: <u>http://www.fairchildsemi.com/packaging/tr/sot89\_tr.pdf</u>.





http://www.fairchildsemi.com/packaging/tr/to92\_tr.pdf.



# Figure 6. 8-Lead, SOIC, JEDEC MS-012, 0.150" NARROW BODY

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

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# PRODUCT STATUS DEFINITIONS

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev. 164